

**2 MHz, 4 Channel × 150 mA WLED/RGB Driver
with Output Disconnect**

Discontinued Product

These parts are no longer in production. The device should not be purchased for new design applications. Samples are no longer available.

Date of status change: July 1, 2024

NOTE: For detailed information on purchasing options, contact your local Allegro field applications engineer or sales representative.

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2 MHz, 4 Channel × 150 mA WLED/RGB Driver with Output Disconnect

FEATURES AND BENEFITS

- Four LED sinks rated for 150 mA each (600 mA total)
- Boost converter with integrated 40 V DMOS switch and OVP—load-dump protection
- 600 kHz to 2.2 MHz switching frequency—ability to operate above the AM band
- Internal bias supply for single-supply operation ($V_{IN}=6.8$ to 21 V)
- 3.5 μ A shutdown current—limits battery drain
- Active current sharing between LED strings for 0.8% current matching and 0.7% accuracy
- PWM dimming with LED PWM duty cycle control
- 4000:1 dimming range
- Extensive fault mode protection schemes:
 - Shorted LED protection against misconnected loads— with true output disconnect
 - Open LED disconnect protects against LED failures
 - External thermistor sensing to limit LED temperature
 - Output overvoltage protection (OVP): 19.5 V default can be adjusted as high as 38 V
 - Open Schottky and open OVP resistor protection against external component failure
 - Input under- and overvoltage protection (UVLO and OVLO) against V_{IN} variation
 - Boost current limit, output short circuit limit, overtemperature protection (OTP), and soft-start

PACKAGE:



28-pin TSSOP with exposed thermal pad (package LP)

Not to scale

DESCRIPTION

The A8511 is a multioutput WLED/RGB driver for backlighting medium-size displays. It is a fully integrated high-brightness (HB) LED driver solution that does not require external power devices to complete the backlighting design criteria. The A8511 integrates FETs for a boost converter as well as four 150 mA current sinks, offering a complete integrated solution at HB LED current levels. LED channels can be tied together for up to 600 mA sink capability. It can work from a single power supply of 6.8 to 21 V and withstand up to 40 V. The boost converter is a constant frequency, current-mode converter.

Operating frequency can be set to 2 MHz avoiding interference with the AM radio band. The integrated boost DMOS switch is rated for 40 V at 3.6 A. PWM dimming allows LED currents to be controlled up to a 1000:1 ratio. Additional 4:1 dimming can be achieved by using the DIM pin.

The A8511 provides protection against output connector shorts through an integrated output disconnect switch. An optional external thermistor can be used to limit LED current based on panel temperature.

The device is supplied in a surface mount, 28-pin TSSOP package (suffix LP), with exposed thermal pad for enhanced thermal dissipation. It is lead (Pb) free, with 100% matte-tin leadframe plating.

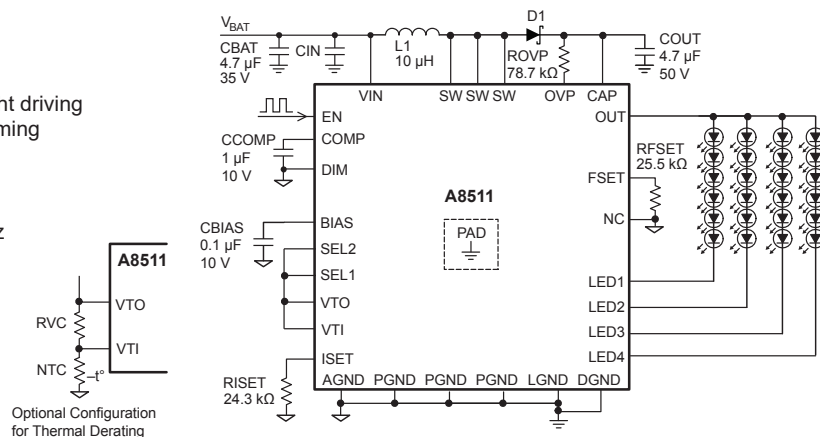
Applications include:

- GPS navigation systems
- Automotive infotainment
- Back-up camera displays
- Cluster backlighting
- Portable DVD players
- Industrial LCD displays

Typical Application

Figure 1. LCD monitor backlight driving 4 LED strings. On/off and dimming control using ENABLE pin.

- Current = 50 mA per string
- OVP = 35 V nominal
- Switching frequency = 2 MHz



SELECTION GUIDE

Part Number	Operating Ambient Temperature Range, T_A	Packing
A8511GLPTR-T	–40°C to 105°C	Contact Allegro
A8511KLPTTR-T	–40°C to 125°C	4000 pieces per 13-in. reel



ABSOLUTE MAXIMUM RATINGS*

Characteristic	Symbol	Notes	Rating	Units
SW, OVP, CAP, OUT Pins			–0.3 to 40	V
LED1 through LED4 Pins			–0.3 to 21	V
VIN Pin	V_{IN}	Steady state	–0.3 to 34	V
		Transient < 1 s	40	V
DIM Pin	V_{DIM}		–0.3 to 6	V
Remaining Pins			–0.3 to 7	V
Operating Ambient Temperature	T_A	Range G	–40 to 105	°C
		Range K	–40 to 125	°C
Maximum Junction Temperature	$T_J(\text{max})$		150	°C
Storage Temperature	T_{stg}		–55 to 150	°C

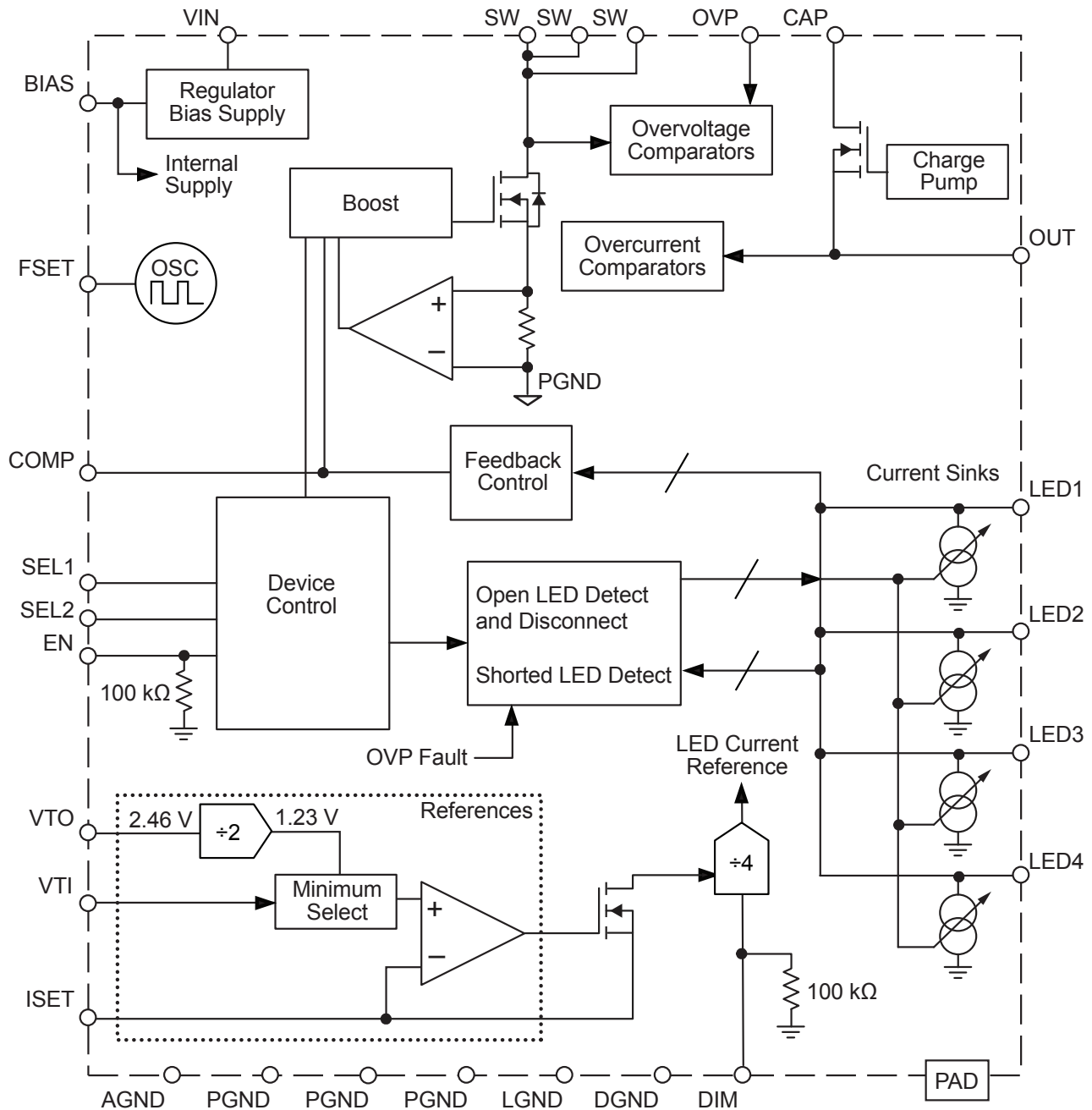
*Stresses beyond those listed in this table may cause permanent damage to the device. The absolute maximum ratings are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the Electrical Characteristics table is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

THERMAL CHARACTERISTICS

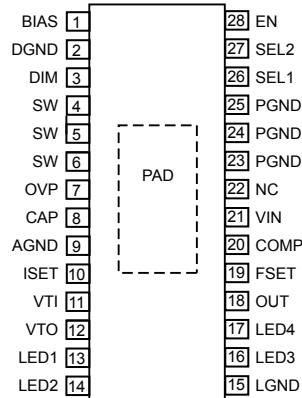
Characteristic	Symbol	Test Conditions*	Value	Units
Package Thermal Resistance	$R_{\theta JA}$	4-layer PCB based on JEDEC standard	28	°C/W

*Additional thermal information available on Allegro website.

FUNCTIONAL BLOCK DIAGRAM



Pinout Diagram



Terminal List Table

Number	Name	Function
1	BIAS	Output of internal 6 V bias supply. Decouple with a 0.1 μ F ceramic capacitor to DGND.
2	DGND	Digital signal ground. Connect AGND, DGND, LGND, PGND, and PAD using star ground connection.
3	DIM	Sets I_{LED} by adjusting the I_{SET} to I_{LEDx} current gain, A_{ISET} . When $DIM = V_{IL}$, $A_{ISET} = 960$ and when $DIM = V_{IH}$, $A_{ISET} = 240$.
4, 5, 6	SW	DMOS switch drain node. Tie these three pins together on the PCB.
7	OVP	To enable overvoltage protection, connect this pin through a resistor to the CAP pin. The default OVP level, with 0 Ω resistor, is 19.5 V. External resistor can set OVP up to 38 V.
8	CAP	Input connection for output disconnect switch.
9	AGND	Analog signal ground. Connect AGND, DGND, LGND, PGND, and PAD using star ground connection.
10	ISET	Sets the 100% current level through LED strings. Set by value of RISET connected between ISET and AGND.
11	VTI	ISET voltage override. Sets the ISET voltage when $V_{TI} < 1.23$ V. Tie directly to VTO pin to disable this feature. This pin can be used for LED current thermal derating or external analog LED current control. See the Typical Application Circuits section for additional information.
12	VTO	2.46 V output voltage. Use this voltage to bias an external NTC resistor or as a DAC reference. This pin can be used as a logic high signal for the SEL and DIM pins.
13,14,16,17	LEDX	LED current sinks.
15	LGND	Power ground for LED current sinks. Connect AGND, DGND, LGND, PGND, and PAD using star ground connection.
18	OUT	Output connection for output disconnect switch. Connect LED common connection to this pin.
19	FSET	Connect RFSET between FSET and AGND to set boost switching frequency.
20	COMP	Sets boost loop compensation. Connect external compensation capacitor between COMP and AGND for boost converter stability.
21	VIN	Input supply for the device. Decouple with a 0.1 μ F ceramic capacitor.
22	NC	Not connected internally. It is recommended to connect this pin to external ground.
23, 24, 25	PGND	Power ground. Connect AGND, DGND, LGND, PGND, and PAD using star ground connection.
26	SEL1	SEL1 and SEL2 together select which LED strings are enabled. See Functional Description section.
27	SEL2	
28	EN	Enable and PWM LED current control. Apply logic-level PWM for PWM-controlled dimming mode.
–	PAD	Exposed thermal pad. Connect AGND, DGND, LGND, PGND, and PAD using star ground connection. Connect to PCB copper layer for enhanced heat dissipation.

ELECTRICAL CHARACTERISTICS: Valid using circuit shown in figure 1; $V_{IN} = 12\text{ V}$, $EN = SEL1 = SEL2 = 5\text{ V}$, $R_{ISET} = 7.87\text{ k}\Omega$, $R_{FSET} = 24.3\text{ k}\Omega$, VTO shorted to VTI guaranteed over the full operating temperature range with $T_A = T_J$, typical specifications are at $T_A = 25^\circ\text{C}$; unless otherwise noted

Characteristics	Symbol	Test Conditions	Min.	Typ.	Max.	Unit
GENERAL						
Input Voltage Range	V _{IN}		8	–	21	V
Undervoltage Lockout Threshold	V _{UVLO(th)}	V _{IN} falling	5.7	6.5	6.8	V
UVLO Hysteresis Window	V _{UVLO(hys)}		0.21	0.55	0.81	V
Overvoltage Lockout Threshold	V _{OVLO(th)}	V _{IN} rising	29	32	34	V
Supply Current	I _S	2 MHz switching at no load	4	11	15	mA
		EN = V _{IL} , in shutdown, T _A = 25°C, CAP = V _{IN} = SW = OVP = 16 V I _S = I _{VIN} + I _{SW} + I _{CAP} + I _{OVP}	–	3.5	6	μA
		EN = V _{IL} , in shutdown, T _A = –40°C to 125°C, CAP = V _{IN} = SW = OVP = 16 V, I _S = I _{VIN} + I _{SW} + I _{CAP} + I _{OVP}	–	3.5	10	μA
		EN = V _{IL} , not in shutdown, I _S = I _{VIN}	–	2	4	mA
LOGIC INPUT LEVELS (DIM, EN, SELX PINS)						
Input Voltage Level – Low	V _{IL}		–	–	0.4	V
Input Voltage Level – High	V _{IH}		1.5	–	–	V
Input Leakage Current (EN, DIM pins)	I _{lk1}	V _{DIM} , V _{EN} = 5 V	30	50	70	μA
Input Leakage Current (SELx pins)	I _{lk2}	V _{SELx} = 5 V	–	–	1	μA
OVERVOLTAGE PROTECTION						
Output Overvoltage Threshold	V _{OVP(th)}	OVP pin connected to OUT pin	18	19.5	21	V
OVP Sense Current	I _{OVPH}		183	200	217	μA
OVP Leakage Current	I _{OVP(lkg)}	V _{OVP} = 18 V, EN = V _{IL} , in shutdown	–	0.1	1	μA
BOOST SWITCH						
Switch On Resistance	R _{SWDS(on)}	I _{SW} = 2 A	40	100	300	mΩ
Switch Leakage Current	I _{SW(lkg)}	V _{SW} = 21 V	–	0.1	10	μA
Switch Current Limit	I _{SW(lim)}		3	3.6	5.3	A
LED CURRENT SINKS						
LEDx Regulation Voltage	V _{LED}	V _{LED1} = V _{LED2} = V _{LED3} = V _{LED4}	–	850	1100	mV
I _{ISET} to I _{LEDx} Current Gain	A _{ISET}	I _{ISET} = 156 μA, DIM = V _{IL}	915	963	1011	A/A
		I _{ISET} = 156 μA, DIM= V _{IH}	229	242	255	A/A
ISET Pin Voltage	V _{ISET}		1.13	1.23	1.33	V
VTO Pin Voltage	V _{TO}	I _{VTO} = 1 mA	2.00	2.46	2.65	V
VTO Pin Current Maximum	I _{TO(max)}	I _{VTO} increased until V _{TO} drops by 1%	1.5	2.4	5	mA
VTI Pin Voltage	V _{TI(falling)}	V _{TI} start >1.34 V, VTI pin voltage decreasing before control changes to VTI pin	1.00	1.12	1.23	V
	V _{TI(rising)}	V _{TI} start <1 V VTI pin increasing before changing to internal reference	1.13	1.235	1.34	V

Continued on the next page...

ELECTRICAL CHARACTERISTICS (continued): Valid using circuit shown in figure 1; $V_{IN} = 12\text{ V}$, $EN = SEL1 = SEL2 = 5\text{ V}$, $R_{ISET} = 7.87\text{ k}\Omega$, $R_{FSET} = 24.3\text{ k}\Omega$, VTO shorted to VTI, guaranteed over the full operating temperature range with $T_A = T_J$, typical specifications are at $T_A = 25^\circ\text{C}$; unless otherwise noted

Characteristics	Symbol	Test Conditions	Min.	Typ.	Max.	Unit
ISET Pin Allowable Current Range	I_{ISET}		20	–	166	μA
LEDx Accuracy ^[1]	Err_{LED}	$R_{ISET} = 10\text{ k}\Omega$. 100% current ratio, measured as the average of V_{LEDx} , for LED1 through LED4, with $V_{LEDx} = 0.85\text{ V}$, $T_A = T_J = 0\text{ to }125^\circ\text{C}$	–	0.7	3	%
LEDx Matching ^[2]	Δ_{LEDx}	$I_{ISET} = 125\text{ }\mu\text{A}$, 100% current ratio, with $V_{LEDx} = 0.85\text{ V}$	–	0.8	3	%
LED Switch Leakage Current	$I_{S(lkg)}$	$V_{LEDx} = 17.5\text{ V}$, $EN = V_{IL} = 0\text{ V}$	4.8	8.75	12.8	μA
LEDx Short Detect Voltage Threshold	V_{LEDSC}	On any LEDx pin, forces latched shutdown	17.5	19	21	V
Output Disconnect Switch On-Resistance	$R_{ODS(on)}$	$V_{IN} = 8\text{ V}$, $I_{OUT} = 400\text{ mA}$, $T_J = 125^\circ\text{C}$	–	2	4	Ω
OSCILLATOR						
FSET Pin Voltage	V_{FSET}	$R_{FSET} = 24.3\text{ k}\Omega$	1.14	1.235	1.33	V
Frequency	f_{OSC}	$R_{FSET} = 24.3\text{ k}\Omega$	1.8	2.1	2.4	MHz
		$R_{FSET} = 51.1\text{ k}\Omega$	0.850	1	1.285	MHz
		$R_{FSET} = 84.5\text{ k}\Omega$	0.5	0.6	0.8	MHz
Minimum Switch Off-Time	$t_{off(min)}$		–	60	110	ns
Minimum Switch On-Time	$t_{on(min)}$		–	60	110	ns
SOFT-START						
Soft-Start Boost Current Limit	$I_{SWSS(lim)}$	Initial soft-start current for boost switch	0.4	0.6	0.75	A
Soft-Start LEDx Current	I_{LEDSS}	Current through each enabled LEDx pin during soft-start, $R_{ISET} = 7.87\text{ k}\Omega$	4	7.5	12	mA
PWM TIMING ON EN PIN						
Maximum PWM Dimming Off-Time	t_{PWML}	Measured while $EN = \text{low}$, during dimming control, and internal references are powered on (exceeding t_{PWML} results in shutdown)	–	131,072	–	f_{SW} cycles
Minimum PWM On-Time	t_{PWMH}		–	–	6	μs
PWM High to LED On Delay	$t_{dPWM(on)}$	Time between PWM enable and when LED current reaches 90% of maximum, with internal references enabled and t_{PWML} not exceeded	–	3	–	μs
PWM Low to LED Off Delay	$t_{dPWM(off)}$	Time between EN going low and when LED current reaches 10% of maximum, with internal references enabled and t_{PWML} not exceeded	–	0.5	–	μs
THERMAL PROTECTION (TSD)						
Thermal Shutdown Threshold ^[3]	T_{TSD}	Device temperature rising	150	172	195	$^\circ\text{C}$
Thermal Shutdown Hysteresis ^[3]	$T_{TSD(hys)}$		15	20	25	$^\circ\text{C}$

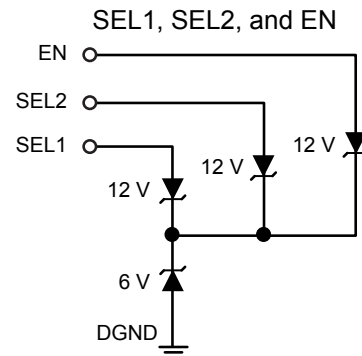
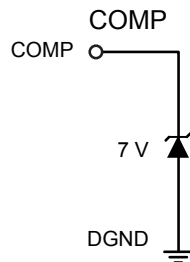
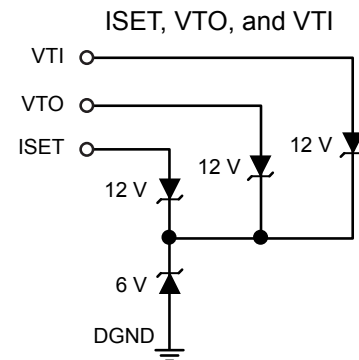
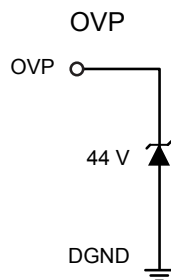
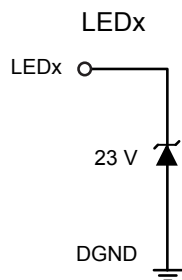
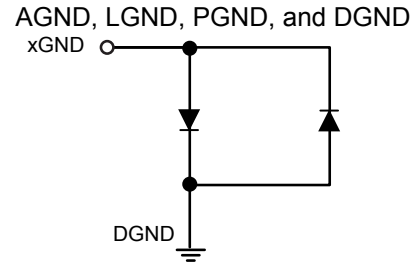
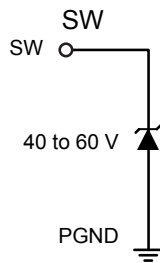
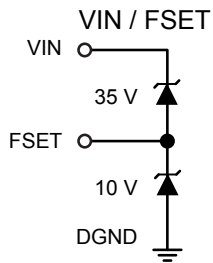
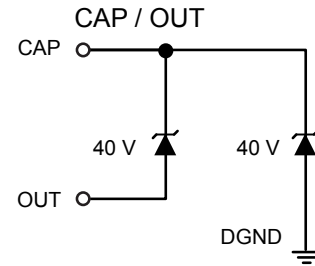
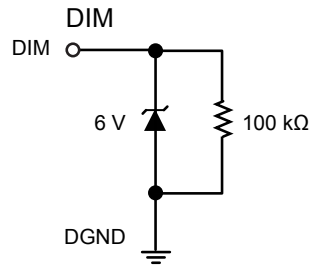
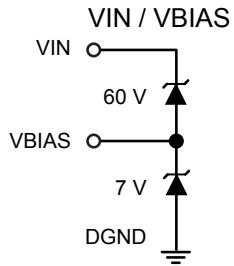
^[1] LED accuracy is defined as $(I_{ISET} \times 960 - I_{LED(av)}) / (I_{ISET} \times 960)$, $I_{LED(av)}$ measured as the average of I_{LED1} through I_{LED4} .

^[2] LED current matching is defined as $(I_{LEDx} - I_{LED(av)}) / I_{LED(av)}$, with $I_{LED(av)}$ as defined in footnote 1.

^[3] Guaranteed by design and characterization, functional tested in production.

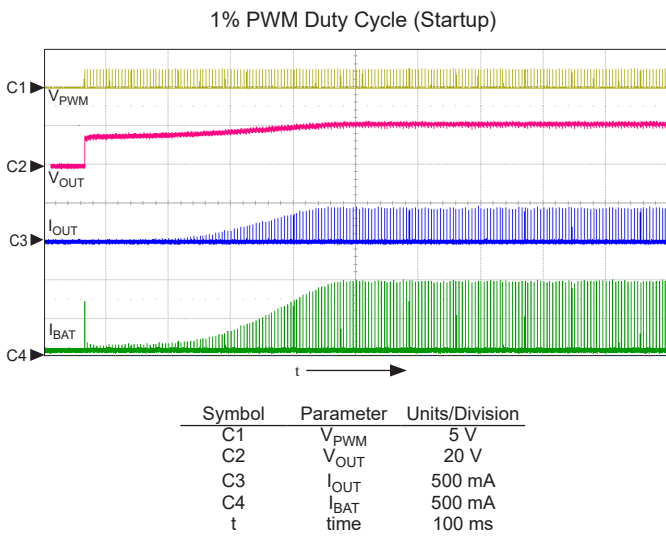
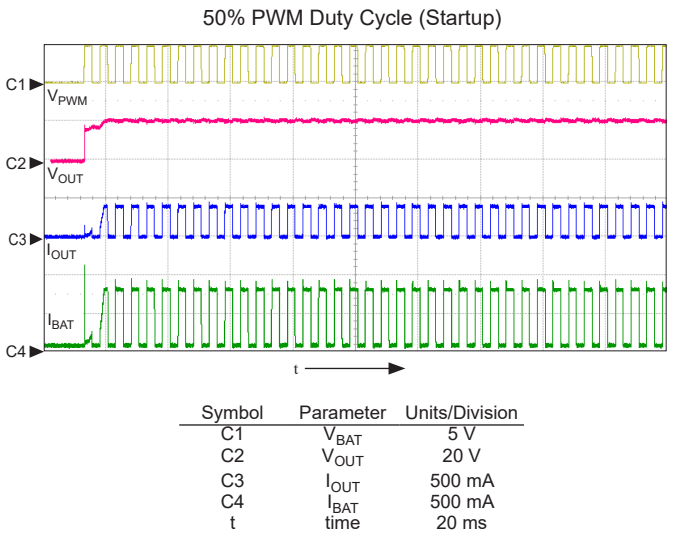
PERFORMANCE CHARACTERISTICS

Electrostatic Discharge Structures
Equivalent ESD on Pins



PERFORMANCE CHARACTERISTICS

PWM Waveforms
 $V_{BAT} = 12\text{ V}$, $I_{OUT} = 400\text{ mA}$, $f_{PWM} = 200\text{ Hz}$
4 channels enabled, 6 LEDs each channel



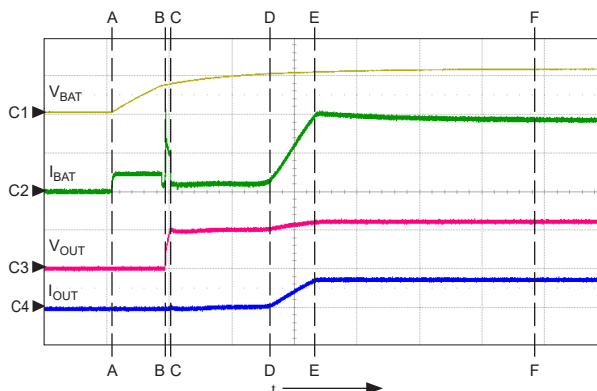
PERFORMANCE CHARACTERISTICS

Startup Waveforms

Soft-Start Turn On Using Rising V_{BAT}

$V_{BAT} = 12V$, $I_{OUT} = 400\text{ mA}$

4 channels enabled, 6 series LEDs each



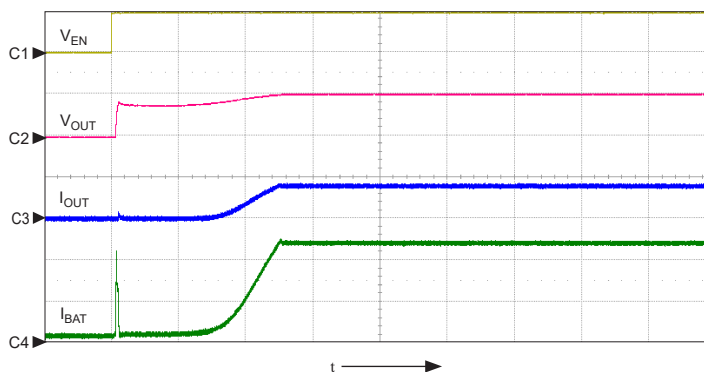
Symbol	Parameter	Units/Division
C1	V_{BAT}	10 V
C2	I_{BAT}	500 mA
C3	V_{OUT}	20 V
C4	I_{OUT}	500 mA
t	time	5 ms

- A. V_{BAT} voltage slowly increased with EN held high.
- A-B. Input bulk capacitor C_{BAT} and boost output capacitor C_{OUT} are charged to V_{UVLO} .
- B. V_{BAT} reaches V_{UVLO} , and enables A8511 through soft-start.
- B-C. During soft-start period, boost switch peak current is limited to 600 mA and LED current to $1/20$ of desired level. Narrow current spike at B is due to parasitic capacitance from OUT to ground and C_{BIAS} . COMP pin is held low during soft-start.
- D. After V_{OUT} reaches a level such that all LED pins $> 0.75\text{ V}$, the A8511 comes out of soft-start.
- C-E. After initial rise of V_{OUT} , the capacitor C_{COMP} starts charging slowly (C_{COMP} not shown).
- E. V_{COMP} reaches desired level for stable operation.
- F. A8511 and LEDs reach thermal steady state.

Turn On Using EN Pin

$V_{BAT} = 8V$, $I_{OUT} = 400\text{ mA}$

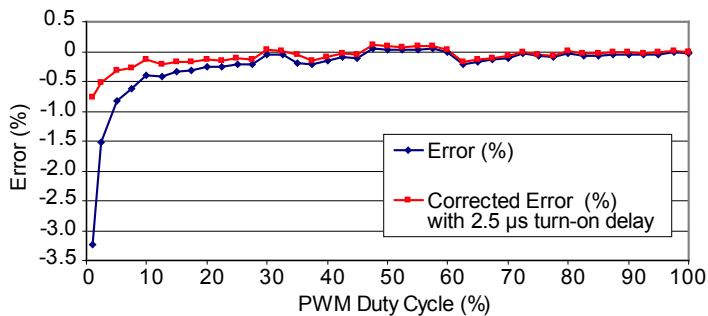
4 channels enabled, 6 series LEDs each



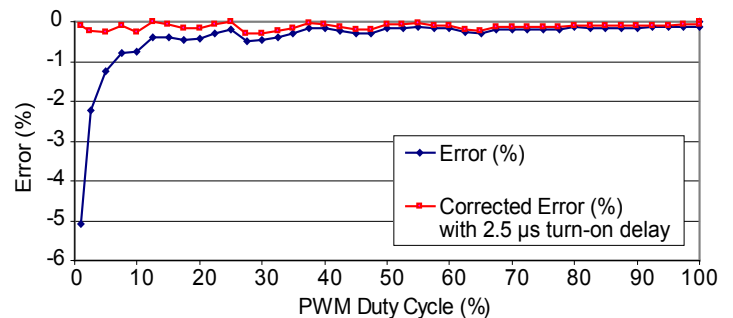
Symbol	Parameter	Units/Division
C1	V_{BAT}	5 V
C2	V_{OUT}	20 V
C3	I_{OUT}	500 mA
C4	I_{BAT}	500 mA
t	time	2 ms

PERFORMANCE CHARACTERISTICS

LED Current Error at 100 Hz PWM



LED Current Error at 200 Hz PWM

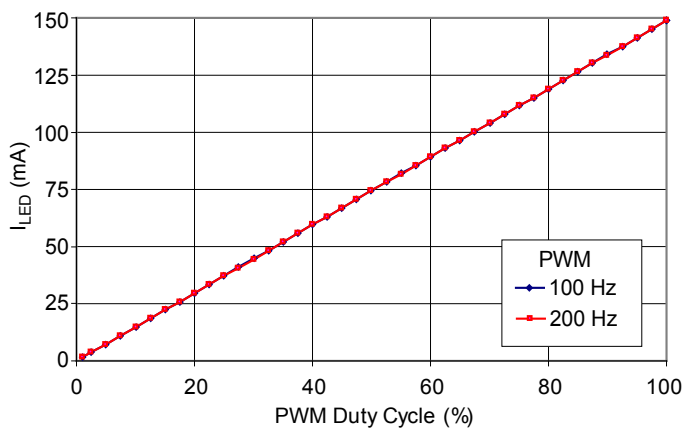


The LED Current Error graph shows the effect of PWM duty cycles on LED current error, according to the relationship:

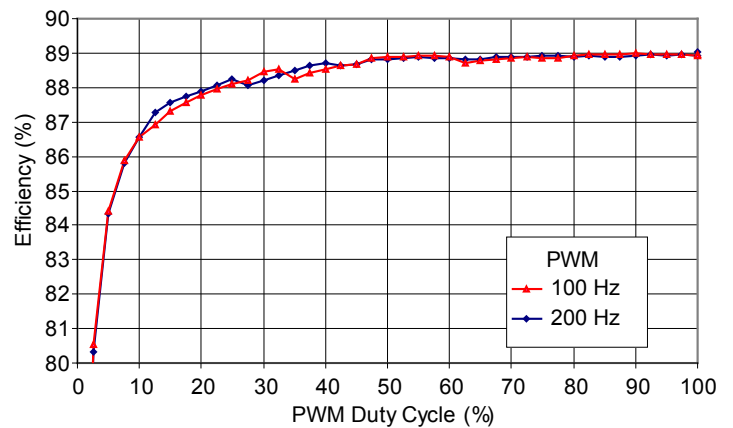
$$\text{Error (\%)} = (I_{\text{SET}} \times 960 \times \text{PWM Duty cycle} - I_{\text{LED(av)}}) / (I_{\text{SET}} \times 960 \times \text{PWM Duty cycle})$$

At lower PWM duty cycles, turn-on delay adversely affects LED current accuracy. This accuracy can be improved by extending the applied PWM signal by 2.5 μs. For example, at 100 Hz PWM and 1% PWM duty cycle, the on-time would be 100 μs. The effects of that turn-on delay could be offset by applying a 102.5 μs PWM pulse.

LED Current versus PWM Duty Cycle



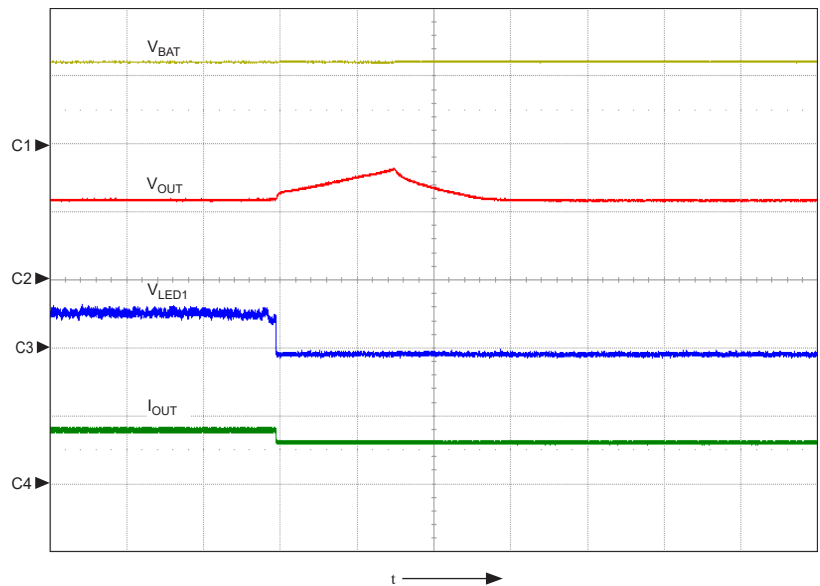
Efficiency versus PWM Duty Cycle



PERFORMANCE CHARACTERISTICS

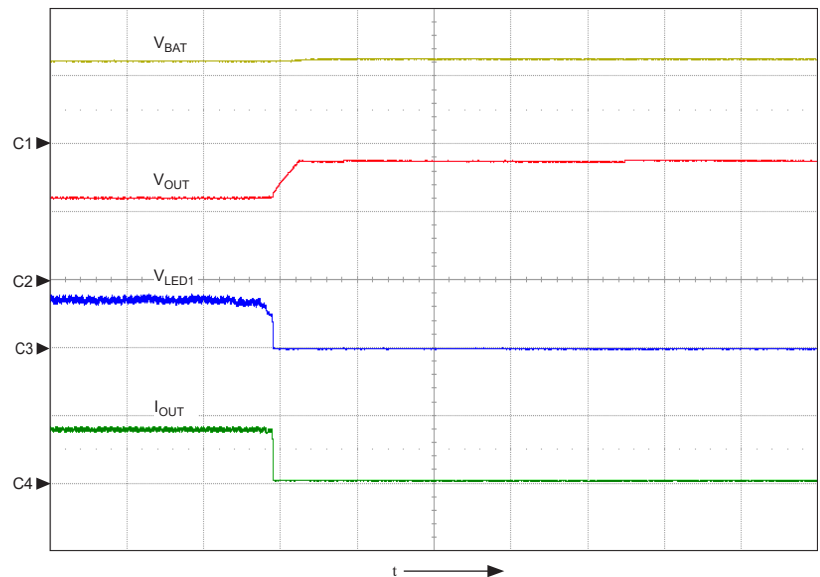
Output LED Open Protection
 $V_{BAT} = 12\text{ V}$, $I_{LED} = 100\text{ mA}$ per LED string, EN = high

LED string #1 disconnected. V_{OUT} increases to OVP level, and LED string #1 is removed from regulation. The rest of the LED strings continue to function normally.



Symbol	Parameter	Units/Division
C1	V_{BAT}	10 V
C2	V_{OUT}	20 V
C3	V_{LED1}	1 V
C4	I_{OUT}	500 mA
t	time	100 µs

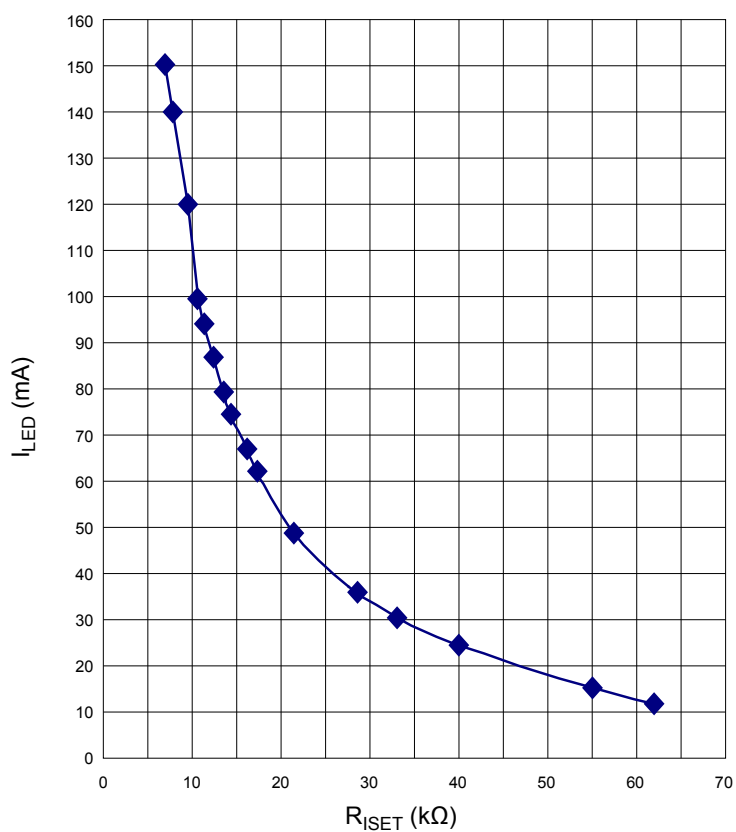
All four LED strings disconnected simultaneously. V_{OUT} increases to OVP level, and all LED strings are removed from regulation.



Symbol	Parameter	Units/Division
C1	V_{BAT}	10 V
C2	V_{OUT}	20 V
C3	V_{LED1}	1 V
C4	I_{OUT}	500 mA
t	time	100 µs

PERFORMANCE CHARACTERISTICS

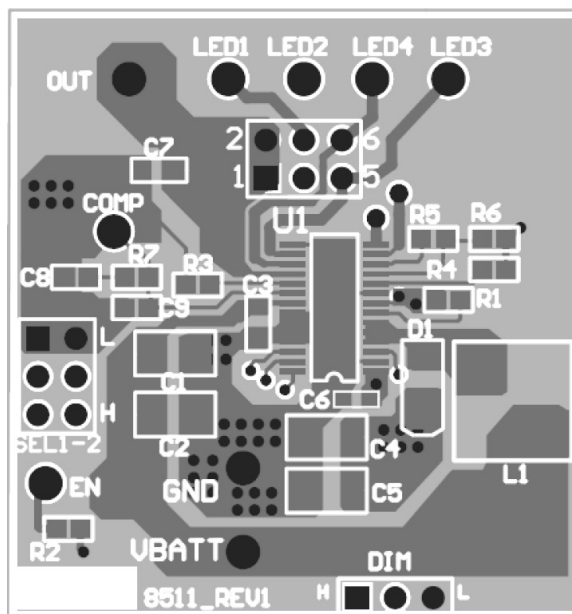
ISET Characterization

LED Current versus R_{ISET} 

PERFORMANCE CHARACTERISTICS

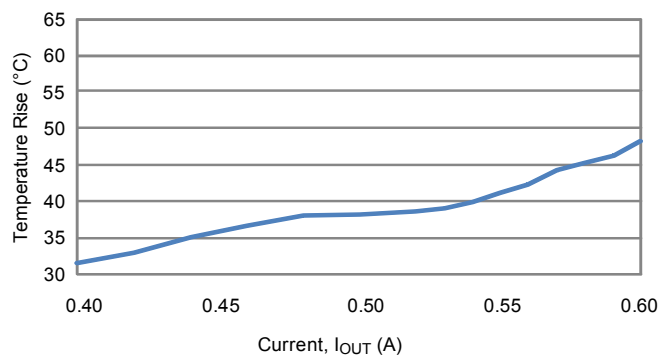
Thermal Dissipation Characterization

Case temperature rise testing was performed on the standard A8511 evaluation board (figure at right). This is a 4-layer board composed of standard FR4 material.



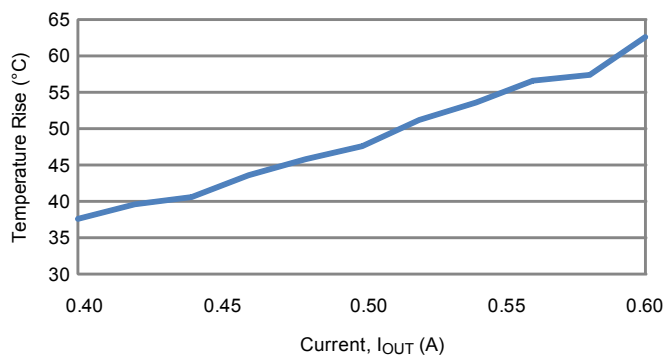
Package Case Temperature Rise versus Total Output Current

$V_{IN} = 12\text{ V}$, $V_{OUT} = 20\text{ V}$



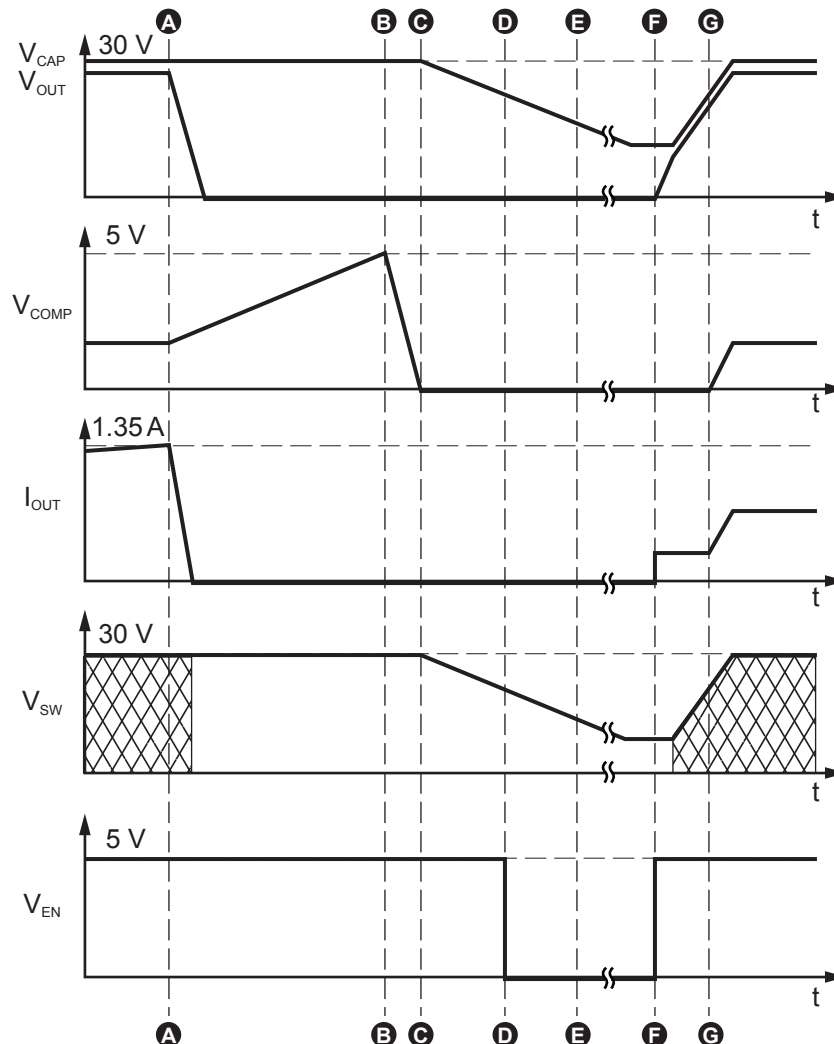
Package Case Temperature Rise versus Total Output Current

$V_{IN} = 12\text{ V}$, $V_{OUT} = 25\text{ V}$



PERFORMANCE CHARACTERISTICS

Disconnect Switch Overcurrent Fault Timing Diagram



- A. Overcurrent on disconnect switch is detected and disconnect switch latches off. Boost is turned off when $>3\text{ V}$ is detected across the disconnect switch. LEDs stop sinking current because there is insufficient voltage across them.
- B. COMP pin reaches lockout level. LEDs are internally turned off and the COMP pin is discharged.
- C. COMP pin reaches ground voltage, LEDs are internally turned on, in soft-start mode, and boost is put into soft-start mode. Boost and LEDs remain off because V_{OUT} is still at ground

- potential due to the disconnect switch being latched off.
- D. User turns off EN.
- E. The A8511 shuts down when EN is off for more than 131,072 clock cycles. If any other fault conditions were present prior to shutdown, such as: open LED, TSD, shorted LED, or secondary OVP, these are now cleared and the part is ready to be re-enabled.
- F. User re-enables operation. A8511 enters soft-start mode.
- G. Soft-start mode finished.

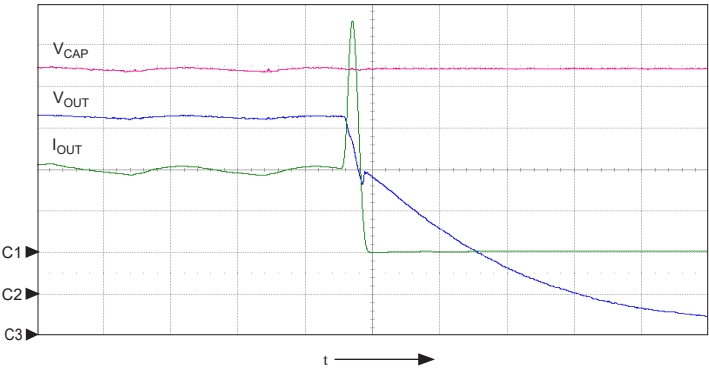
PERFORMANCE CHARACTERISTICS

Fault Protection

$V_{BAT} = 12\text{ V}$, $I_{LED} = 100\text{ mA}$ per string
4 channels enabled, 8 series LEDs each

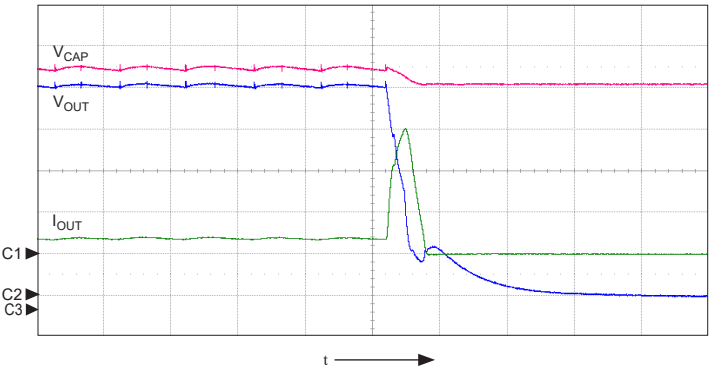
V_{OUT} to LED1 Short

(LED Short Detect activated, causing a latched shutdown)



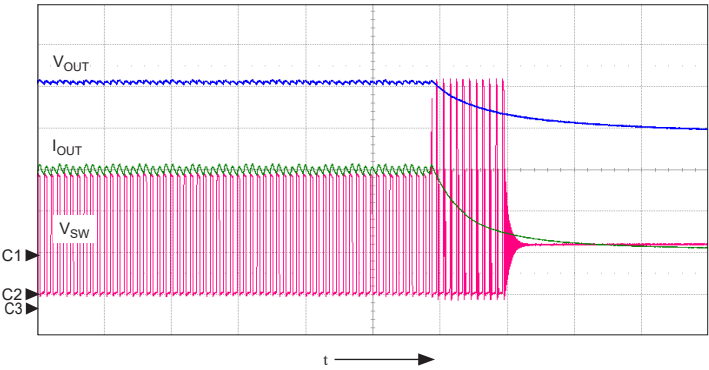
V_{OUT} to Ground Short

(Output Disconnect Switch opens to prevent any damage)



Open Schottky Diode Disconnect

(Secondary OVP activated, causing a latched shutdown)



FUNCTIONAL DESCRIPTION

Description

The A8511 is a multioutput WLED/RGB driver for display backlighting. It uses a current mode boost converter which operates at a constant frequency. The boost switching frequency can be set from 600 kHz to 2.2 MHz by an external resistor connected across FSET and AGND. The integrated boost DMOS switch is rated for 40 V at 3.6 A. This switch is protected against overvoltage and provides pulse-by-pulse current limiting independently of boost converter duty cycle.

The A8511 has 4 well-matched current sinks, which provide regulated current through the load LEDs for uniform display brightness. All LEDx sinks are rated for 21 V to allow PWM dimming control.

Frequency Selection

The switching frequency on the SW pin, f_{SW} , can be set by applying the following equation:

$$f_{SW} = 51 / R_{FSET} \quad (1)$$

where f_{SW} is in MHz, and R_{FSET} is in k Ω .

LED Selection

Which LED strings are enabled is determined by the combined settings of the SEL1 and SEL2 pins, according to the following table:

LED Channel Selection		
SEL1 Pin	SEL2 Pin	Enabled LEDx Outputs
Low	Low	Only LED1
High	Low	LED1 and LED2
Low	High	LED1, LED2, and LED3
High	High	All channels

LED strings that are connected to the A8511, but are not enabled through the SELx pins, may cause a shutdown if the voltage on the corresponding LEDx pins exceeds V_{LEDSC} . Refer to the LED Short Detect section for further details. Unused LEDx pins can be left open or connected to ground.

Use matched forward voltage LEDs for better efficiency.

The application circuit shown in figure 1 is a boost converter and the output voltage is always higher than the battery voltage. Therefore, the quantity of LEDs per string should be such that the required output voltage is higher than the maximum battery voltage. If the battery voltage is higher than the output voltage, the A8511 will switch with minimum pulse width, and the actual output voltage will be higher than the required voltage. The excess voltage will be dropped across the LED strings. This lowers efficiency and increases power dissipation, resulting in higher device temperature. If battery voltage must be higher than required output voltage, use a SEPIC converter, as shown in figure 9.

Soft-Start and Compensation

At startup, the output capacitor is discharged and the A8511 enters soft-start. The boost current is limited to 0.6 A and all active LEDx pins sink $1/20$ of the set current until all the enabled LEDx pins reach 0.75 V. When the A8511 comes out of soft-start, the boost current and the LEDx pin currents are set to normal. The output capacitor charges to voltage required to supply full LEDx currents within a few cycles. Once V_{OUT} reaches the required level, LEDx current toggles between 0 and 100% in response to PWM signals. Soft-start behavior on evaluation boards is shown in the Performance Characteristics section.

LED Current Setting

The maximum LED current can be up to 150 mA per channel and is set through the ISET pin. Connect a resistor, R_{ISET}, between this pin and AGND to set the reference current level, I_{ISET}, according to the following formula:

$$I_{ISET} = 1.235 / R_{ISET}, \quad (2)$$

where I_{ISET} is in mA and R_{ISET} is in kΩ.

This current is multiplied internally with a gain of 960, and mirrored on all enabled LED pins. This sets the maximum current through the LEDs, referred as the *100% current*.

Dimming

The LED current can be reduced from the 100% current level by three alternative dimming methods:

- PWM dimming using the EN pin. PWM dimming is performed by applying an external PWM signal on the EN pin. When the EN pin is pulled high, the A8511 turns on and all enabled LEDs sink 100% current. The sequence is shown in figure 2. For optimal accuracy, the external PWM signal should be in the range 100 to 300 Hz. The slight delay between PWM signal and the LED current causes an error. To compensate for the error, a small turn-on delay should be added to the PWM signal as shown on page 10 of the Performance Characteristics section. When EN is pulled low, the boost converter and LED sinks are turned off. The compensation (COMP) pin is floated, and critical internal circuits are kept active. If EN is pulled low for more than t_{PWML}, the device enters shutdown mode and clears all internal fault registers. As an example, for a 2 MHz clock, the maximum PWM low period while avoiding shutdown is 65 ms.
- Analog dimming using the DIM pin. When the DIM pin is pulled low, the LED sinks draw 100 % current; when the pin is pulled high, the LED current level drops to 25%.
- Analog dimming using the VTI pin. External DC voltage can be applied to the VTI pin to control LED current. LED current varies as a function of voltage on the VTI pin. This configuration is shown in figure 5.

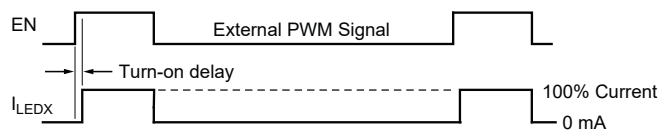


Figure 2. Timing diagram of external PWM signal and LED current

LED Open Detect

When any LED string opens, the boost circuit increases the output voltage until it reaches the overvoltage protection level. The OVP event causes any LED string that is not in regulation to be locked-out from regulating the loop. By removing the open LED from controlling the boost, the output voltage returns to normal operating voltage. Every OVP event retests all LED strings. An EN low signal does not reset the LED string regulation lock unless it shuts down the device (exceeds t_{PWML}). The locked-out LED pins always attempt to sink desired current regardless of lock-out state.

LED Short Detect

Any LED pin that has a voltage exceeding V_{LEDSC} will force the device to disable the boost circuit and LEDx outputs until EN shuts down the A8511 (EN low exceeds t_{PWML}). This protects the LEDx pins from potentially hazardous voltages when multiple LEDs are shorted in one string.

Overvoltage Protection

The A8511 has overvoltage protection (OVP) and open Schottky diode protection.

The OVP has a default level of 19.5 V and can be increased up to 38 V by the selection of an external resistor, as shown in figure 3. When the current through OVP pin exceeds 200 μA, the OVP comparator goes low. When V_{OUT} falls and current through the OVP pin drops below 165 μA, the OVP is released.

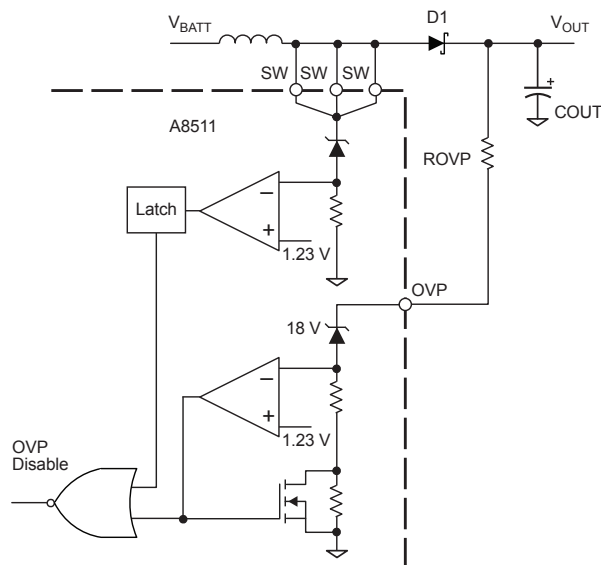


Figure 3. Overvoltage protection (OVP) circuit

The following equation can be used to determine the resistance for setting the OVP level:

$$R_{OVP} = (V_{OVP} - 19.5) / 200 \mu A \quad (3)$$

where V_{OVP} is the target typical OVP level, and R_{OVP} is the value of the external resistor, in Ω .

A8511 has secondary overvoltage protection to protect internal switches in the event of an open diode condition. Open Schottky diode detection is implemented by detecting overvoltage on the SW pin. If voltage on the SW pin exceeds the device safe operating voltage rating, the A8511 disables and remains latched. The IC must shut down before it can be reenabled.

Overcurrent Protection

The boost switch is protected with pulse-by-pulse current limiting at 3.6 A. The output disconnect switch protects against output overcurrent. At 1.35 A typical, the A8511 disables. This process is detailed in the Disconnect Switch Overcurrent Fault Timing diagram in the Performance Characteristics section, page 14.

In some instances, when the LEDs are connected by long wires and also some output capacitance (such as ESD capacitors) is present, a clamping diode on the output must be used. This diode will prevent the output from momentarily going negative during a short circuit condition. The diode must be chosen such that its reverse breakdown voltage is higher than normal operating voltage and its reverse current leakage is small.

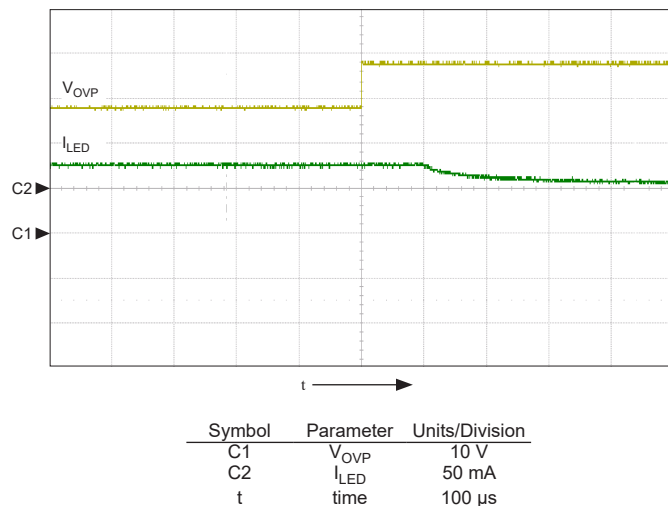


Figure 4. Output overvoltage protection (OVP) operation

Input UVLO

When V_{IN} rises above the UVLO enable hysteresis ($V_{UVLO(th)} + V_{UVLO(hys)}$), the A8511 is enabled. It is disabled when V_{IN} falls below $V_{UVLO(th)}$ for more than 50 μs . This lag is to avoid shutting down because of momentary glitches in the power supply.

Input OVLO

When V_{IN} rises above $V_{OVLO(th)}$ for more than 50 μs , the A8511 is disabled, the boost converter shuts down instantly, and LED current falls gradually with the CAP pin capacitor. When V_{IN} falls below $V_{OVLO(th)}$ and EN is high, the device is reenabled.

Thermal Derating

Thermal derating can be achieved by connecting an NTC thermistor between VTI and ground, as shown in figure 5. When the A8511 is enabled and $V_{TI} > 1.1$ V, 100% current for the LEDs is controlled by the ISET and DIM pins. When V_{TI} falls below 1.1 V, V_{ISET} starts to follow V_{TI} , resulting in I_{LEDX} varying proportionately with V_{TI} represented by the overlap of the dotted and solid curves. The proportion of I_{LED} to V_{TI} , when LED current is controlled through the VTI pin, is calculated as:

$$I_{LEDX} = 960 \times V_{TI} / R_{ISET} \quad (4)$$

where I_{LEDX} is the LEDx pin current in mA, and R_{ISET} is in k Ω .

There is a hysteresis built into the VTI pin circuit, so while V_{TI} is decreasing, there is a delay before proportional change begins if VTI pin voltage starts above 1.1 V. When V_{TI} starts below 1.1 V, or falls below 1.1 V during operation and then starts increasing again V_{ISET} will follow V_{TI} until the voltage reaches 1.23 V.

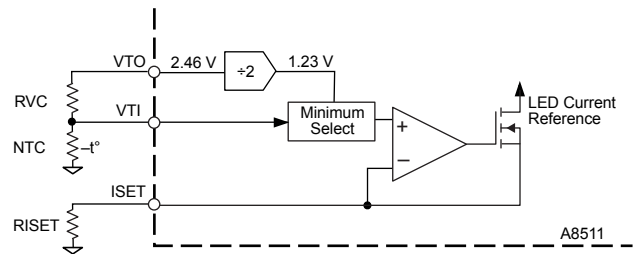


Figure 5. Thermal derating reference circuit

Bias Supply

The BIAS pin provides regulated 6 V for internal circuits. Connect a CBIAS capacitor with a value in the range of 0.1 to 1 μF .

Efficiency Considerations

For better efficiency, use a high-quality inductor with relatively low DCR and core loss.

Use a low forward voltage Schottky diode with relatively low junction capacitance.

Use matched forward voltage LEDs for better efficiency.

The A8511 provides an output disconnect function through a load switch that is connected from the boost converter output (CAP) to LED connection (OUT). This function protects the system against short circuit conditions from common anode LED connection to ground, for both boost and SEPIC configurations.

When comparing the efficiency of the A8511 with an alternate implementation requiring an external input/output disconnect function, the additional power dissipation in this disconnect switch must be considered for a proper comparison. To bypass the disconnect switch, short the CAP pin to the OUT pin to have a direct connection from the boost regulator to the common anode LED node. When the disconnect switch is bypassed, both the boost and the SEPIC implementations are not protected against output short circuit conditions.

Audible Noise Considerations

Multilayer ceramic capacitors cause audible noise when subjected to voltage ripple in the audio frequency range, due to the piezoelectric effect. Ceramic capacitors connected across boost converters can also cause audible noise due to voltage ripple at dimming frequencies. During the PWM dimming off-time, the voltage across the capacitors drops due to leakage through the output disconnect switch and the OVP pin. This voltage is regulated to the desired output level during the PWM dimming

on-time. This voltage ripple may cause audible noise.

Audible noise can be minimized with higher dimming frequency, but at higher dimming frequencies accuracy may be affected, as shown in the Performance Characteristics section. It is recommended to use 200 Hz for optimum performance.

Selecting a sufficiently large capacitor across the boost output can reduce voltage ripple and noise. It is observed that the audible noise below 250 mV ripple is negligible.

The value to select for a boost capacitor can be calculated using the following formula:

$$C \geq \frac{I_{lk} \times (1 - D_{\text{FPWMmin}})}{f_{\text{PWM}} \times 0.25} \quad (5)$$

where

I_{lk} is the leakage current; select $I_{lk} = 165 \mu\text{A}$ at a 30 V output and 175 μA at a 40 V output,

D_{FPWMmin} is the minimum dimming PWM duty cycle, and

f_{PWM} is the dimming frequency; typically 200 Hz.

For example, if the dimming frequency is 200 Hz, the minimum dimming PWM duty cycle = 10%, and $V_{\text{OUT}} = 30 \text{ V}$, then select the boost capacitor as:

$$C = \frac{165 \mu\text{A} \times (1 - 0.1)}{200 \times 0.25} = 3 \mu\text{F}$$

The capacitance of ceramic capacitors drops with DC bias. Use an appropriate capacitor to get at least 3 μF at 30 V.

The selection of a ripple voltage of 0.25 V is based on a typical MLCC. This ripple level depends on the type and construction of the MLCC. Increase the boost capacitor if noise exists at 0.25 V.

APPLICATION INFORMATION

Design Example

This section provides a method for selecting component values when designing an application using the A8511.

Assumptions

For the purposes of this example, the following are given as the application requirements:

- V_{BAT} : 8 to 18 V
- Quantity of LED channels, $\#_{CHANNELS}$: 3
- Quantity of series LEDs per channel, $\#_{SERIESLEDS}$: 8
- LED current per channel, I_{LED} : 80 mA
- Total current all channels, $I_{OUT} = I_{LED} \times \#_{CHANNELS}$
- V_f at 80 mA: 3 to 3.4 V
- f_{SW} : 2 MHz
- $T_A(\text{max})$: 65°C

Dimming

The A8511 can work with wide range of PWM frequencies. A small delay between the PWM signal and the LED current may have a noticeable effect at high PWM frequencies combined with low PWM duty cycles. For example, at 100 Hz and 10% PWM duty cycle, the PWM on-period is 1 ms. In that period, the delay causes only a 0.6% error. If the PWM frequency is 1 kHz, this error is 6%. However, the error caused by the turn-on delay can be decreased by increasing the applied PWM duty cycle as shown on page 10 in the Performance Characteristics section.

Procedure

The procedure consists of selecting the appropriate configuration and then the individual component values, in an ordered sequence.

1. Identify the SELx pins to use. For 3 channels:
 - connect pin SEL2 to V_{TO}
 - connect pin SEL1 to ground
2. Connect LEDs to pins LED1 through LED3 (leave pin LED4 open).
3. Select resistor R_{ISET} (connected between pin ISET and AGND). Given $I_{LED} = 80$ mA and $A_{ISET} = 960$, then:

$$R_{ISET} = 1.235 / (I_{LED} / A_{ISET}) . \quad (6)$$

Substituting:

$$R_{ISET} = 1.235 / (0.080 / 960) = 14.82 \text{ k}\Omega .$$

Select a common value: 14.7 k Ω , 1%.

4. Select resistor R_{FSET} (connected between pin FSET and AGND). Given:

$$R_{FSET} = 51 / f_{SW} , \quad (7)$$

for a 2 MHz switching frequency, select:

$$R_{FSET} = 51 / 2 = 25.5 \text{ k}\Omega , 1\% .$$

5. Select resistor R_{OVP} (connect to the OVP pin to set the OVP level, $V_{OUT(\text{max})}$). Given $V_f(\text{max}) = 3.4$ V, 0.75 V as the V_{LED} regulation level, and worst case output disconnect switch voltage drop, then:

$$V_{OUT(\text{max})} = (V_f(\text{max}) \times \#_{SERIESLEDS}) + V_{LED} + (R_{ODS(\text{on})} \times I_{LED} \times \#_{CHANNELS}) . \quad (8)$$

Substituting:

$$V_{OUT(\text{max})} = (3.4 \times 8 + 0.75) + (4 \times 0.08 \times 3) = 28.91 \text{ V} .$$

The switch resistance $R_{ODS(\text{on})}$ can be found in the electrical table and is listed as worst case at 4 Ω at high temperatures. To set the output OVP level to 33 V, given an I_{OVPH} of 200 μ A, and $V_{OVP(\text{th})} = 19.5$ V:

$$R_{OVP} = (V_{OVP} - V_{OVP(\text{th})}) / I_{OVPH} . \quad (9)$$

Substituting:

$$R_{OVP} = (33 - 19.5) / 200 \times 10^{-6} = 68 \text{ k}\Omega . \quad (10)$$

6. Select inductor L1. This should assume a maximum boost converter duty cycle, $D(\text{max})$, at $V_{BAT(\text{min})}$ and 90% efficiency, η .

$$D(\text{max}) = 1 - (V_{BAT(\text{min})} \times \eta) / V_{OUT(\text{max})} \quad (11)$$

$$D(\text{max}) = 1 - (8 \times 0.9) / 28.91 = 75\% .$$

Then calculate maximum switch on-time:

$$t_{on(\text{max})} = D(\text{max}) / f_{SW} \quad (12)$$

$$= 0.75 / 2 \times 10^6 = 375 \text{ ns} .$$

Maximum input current can be calculated as:

$$I_{BAT} = (V_{OUT(\text{max})} \times I_{OUT}) / (V_{BAT(\text{min})} \times \eta) \quad (13)$$

$$I_{BAT(\text{max})} = [28.91 \times (0.080 \times 3)] / (8 \times 0.9) = 963 \text{ mA} .$$

Set inductor ripple at 30% of $I_{BAT(max)}$:

$$I_L = I_{BAT(max)} \times I_{Lripple(ideal)} \quad (14)$$

Substituting:

$$\Delta I_L = 0.3 \times 963 = 289 \text{ mA}$$

Given, during switch on-time:

$$V_{BAT(min)} = L \times \Delta I_L \times f_{SW} / D \quad (15)$$

$$8 = L \times 0.289 \times 2 \times 10^6 / 0.75, \text{ and}$$

$$L = 10.4 \mu\text{H}$$

Select a common value: $L_{(used)} = 10 \mu\text{H}$.

It is recommended to select an inductor that can handle a DC current level that is greater than 963 mA, at the peak current level (saturation) of $963 \text{ mA} + 289 \text{ mA} / 2 = 1.11 \text{ A}$. This is to ensure that the inductor does not saturate at any steady state or transient condition, within specified temperature and tolerance ranges. Inductor saturation level decreases with increasing temperature. It is advisable to use an inductor with a saturation level of 2.0 A. The inductor should have a low DC resistance (DCR) and core loss for better efficiency.

7. Select output capacitor C_{OUT} , given:

$$f_{PWM} = 100 \text{ Hz} \quad (16)$$

assuming 20% minimum dimming PWM duty cycle, $D_{PWM(min)}$, and the maximum leakage current through the output disconnect switch at $V_{OUT} = 28 \text{ V}$ is $165 \mu\text{A}$ and $V_{COUTripple} = 0.25 \text{ V}$.

Select the output capacitor as:

$$C_{OUT} = I_{lk} \times (1 - D_{PWM(min)}) / (f_{PWM} \times V_{COUTripple}) \quad (17)$$

Substituting:

$$C_{OUT} = 165 \mu\text{A} \times (1 - 0.2) / (100 \times 0.25) = 5.3 \mu\text{F} \quad (18)$$

Select $6.8 \mu\text{F}$.

The RMS current through C_{OUT} is given by:

$$C_{rms} = I_{OUT} \times \left(\frac{D(max) + (r / 12)}{1 - D} \right)^{1/2} \quad (19)$$

where:

$$r = \Delta I_L / I_{BAT(max)} \quad , \text{ and} \quad (20)$$

$$\Delta I_L = \left(\frac{V_{BAT(min)} \times D}{L_{(used)} \times f_{SW}} \right) \quad (21)$$

Substituting:

$$(80 \text{ mA} \times 3) \times \{ [0.75 + (0.3 / 12)] / (1 - 0.75) \}^{1/2} = 0.422 \text{ A}$$

Select a capacitor with an RMS current rating greater than 0.422 A.

8. Select input capacitor C_{IN} , given:

$$C_{IN} = \Delta I_L / (8 \times f_{SW} \times \Delta V_{INripple}) \quad (22)$$

where $\Delta V_{INripple}$ is the input ripple voltage, which can be assumed to be 1% of V_{BAT} . Then:

$$C_{IN} = 0.3 / (8 \times 2 \times 10^6 \times 0.01 \times 8) = 0.23 \mu\text{F}$$

Select a $2.2 \mu\text{F}$ or higher, 35 or 50 V, ceramic capacitor, X5R or X7R grade.

The RMS current through C_{IN} is given by:

$$I_{INRMS} = (I_{OUT} \times r) / [(1 - D) \times 12^{1/2}] \quad (23)$$

$$= [(80 \text{ mA} \times 3) \times 0.3] / [(1 - 0.75) \times 3.46] = 83 \text{ mA}$$

Select a capacitor with an RMS current rating greater than 83 mA.

9. Select the boost diode D1 (connect between the SW pins and the output). D1 should be a Schottky diode with low forward drop and junction capacitance.

The diode reverse voltage rating should be greater than V_{OUT} . A 40 to 50 V diode rating is recommended.

The diode DC current rating should be greater than I_{OUT} and the peak repetitive current rating should be $> I_{BAT(max)} + \Delta I_L / 2$.

10. Select the compensation capacitor C_{COMP} (connect between the COMP pin and ground). Typically, use a $1 \mu\text{F}$ capacitor to reduce audio hum during PWM dimming.

11. Calculate Power Loss. Calculate power loss at various operating conditions to estimate worst-case power dissipation.

a) Loss in LED drive:

$$I_{LEDx} \times V_{LEDx} \text{ for one string} \\ + (I_{LEDx} \times V_{LEDx(av)} + 0.75 \\ \times \text{quantity of remaining enabled LED strings}), \quad (24)$$

where V_{LEDx} is the regulation voltage of the LEDx pins, 0.75 V typical, and worst-case drop is mismatch due to LED V_f .

A good approximation for $V_{LEDx(av)}$ is 0.8 V. This assumes that some of the remaining strings will regulate below, and some above, a value of 1.55 V. If the predicted LED matching is tighter, then a lower value can be used. If the predicted LED mismatch is large, then a higher value should be used. To get the complete and accurate power dissipation, the user will need to measure each individual LED pin to get the exact V_{LED} voltage:

$$(80 \text{ mA} \times 0.75) + [80 \text{ mA} \times 2 \times (0.8 + 0.75)] = 0.308 \text{ W}$$

b) Loss in low drop-out regulator (LDO) + bias:

$$P_{LDO} = V_{BAT(max)} \times I_{BIAS}, \quad (25)$$

with bias current during switching 17 mA typical.

c) Boost switch conduction loss:

$$I_{BAT(max)}^2 \times D \times R_{DS(on)} \times (1+r^2/12), \quad (26)$$

where:

$$r = \Delta I_L / I_{BAT(max)}. \quad (27)$$

d) Boost switch switching loss:

$$V_{OUT} \times I_{BAT(max)} \times (t_{rise} + t_{fall}) \times f_{SW}. \quad (28)$$

Switch loss calculations assume negligible input gate charge on internal boost MOSFET until $V_{G(th)}$ (gate threshold), compared to the Miller charge; t_{rise} and t_{fall} are measured in the lab under full load conditions. To approximate this value, use 5 ns for rise and fall times.

e) Diode loss:

$$\text{Diode switching loss} = 0.2 \times C_d \times V_{OUT}^2 \times f_{SW}, \quad (29)$$

where C_d is the average junction capacitance of the Schottky diode. Then:

$$\text{Diode conduction loss} = V_f \times I_{BAT(max)} \times (1-D) \quad (30)$$

f) Inductor DCR loss:

$$I_{IN}^2 \times R_{DC} \times (1+r^2/12). \quad (31)$$

g) Inductor core loss:

This value is an estimate. The default value would be 50 mW at 1 A ripple current, and then scaled based on ripple current.

h) Power loss in output disconnect switch:

$$P_{SWDISC(on)} = R_{ODS(on)} \times I_{OUT}^2, \quad (32)$$

If the Output Disconnect Switch On-Resistance, $R_{ODS(on)}$, is 2 Ω , then:

$$P_{SWDISC(on)} = 2 \times 0.24^2 = 0.11 \text{ W}.$$

TYPICAL APPLICATION CIRCUITS

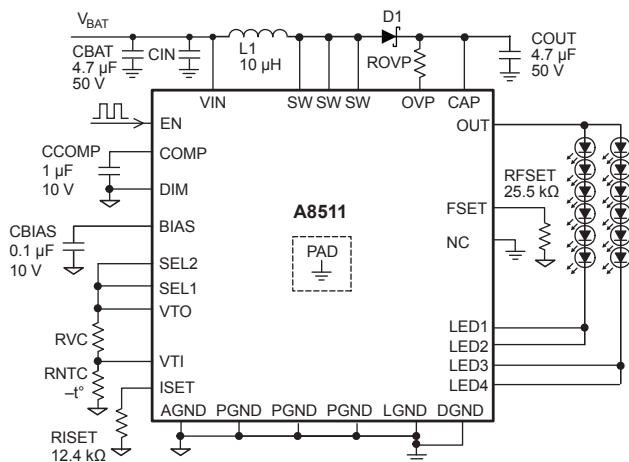


Figure 6. Typical circuit for driving 2 LED strings at up to 35 V at 200 mA per LED string, with thermal derating

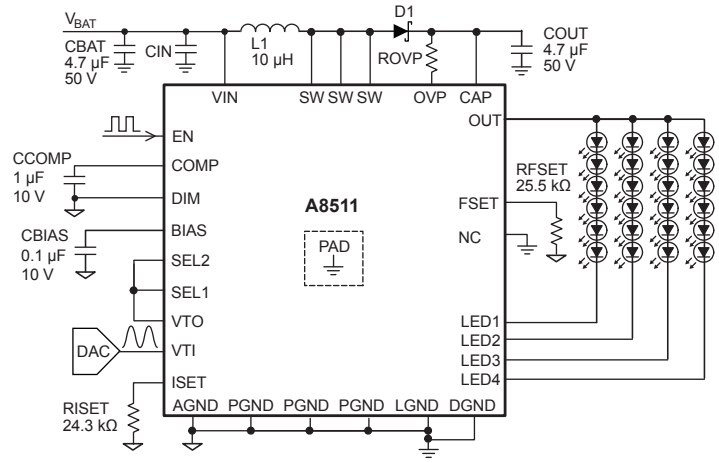


Figure 7. Typical circuit for analog dimming with external DC voltage

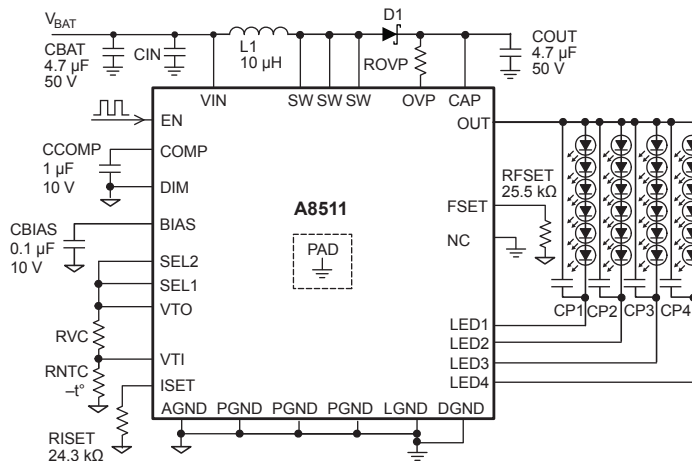


Figure 8. Typical circuit with ESD capacitors across LEDs (CPx ≤ 10 nF), with thermal derating

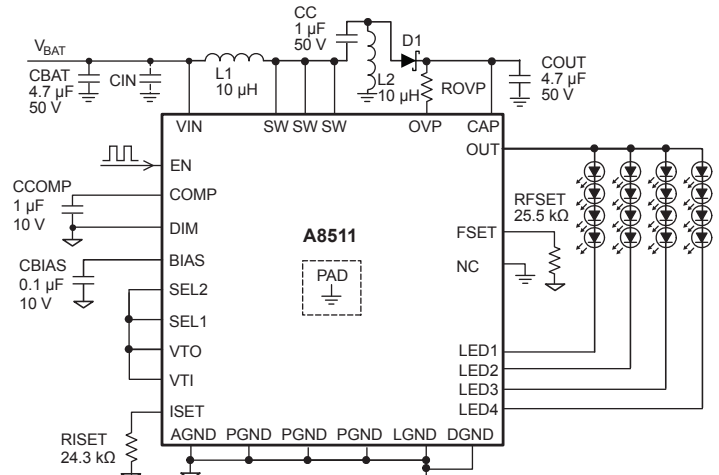
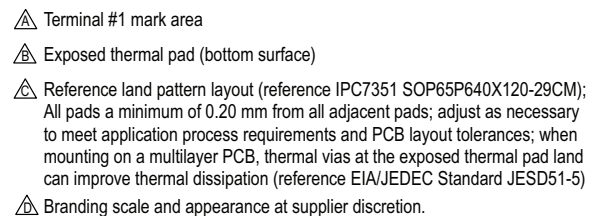


Figure 9. Typical circuit as SEPIC converter (SEPIC converters can provide output voltage higher or lower than the input voltage; this topology can be used if the required output voltage level is within application input voltage range)

Exact case and lead configuration at supplier discretion within limits shown



REVISION HISTORY

Number	Date	Description
–	September 23, 2010	Initial release
1	May 13, 2020	Minor editorial updates
2	May 11, 2022	Updated package drawing (page 24) and minor editorial updates
3	July 1, 2024	Updated product status to Discontinued

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